

## CORRECTION

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## Correction: Thermoelectric properties of Te-doped ternary CuAgSe compounds

P. F. Qiu,<sup>ab</sup> X. B. Wang,<sup>ab</sup> T. S. Zhang,<sup>ab</sup> X. Shi<sup>\*ab</sup> and L. D. Chen<sup>abc</sup>Correction for 'Thermoelectric properties of Te-doped ternary CuAgSe compounds' by P. F. Qiu *et al.*, *J. Mater. Chem. A*, 2015, DOI: 10.1039/c5ta06780d.

Fig. 4 of the above manuscript is incorrect and should be as shown in the figure below.

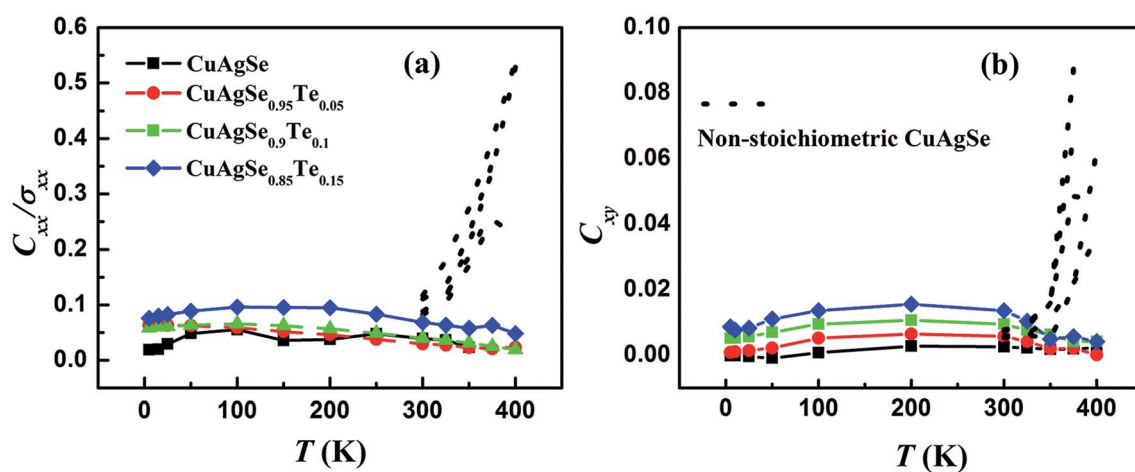


Fig. 4 (a) Temperature dependences of (a)  $C_{xx}/\sigma_{xx}$  and (b)  $C_{xy}$  for  $\text{CuAgSe}_{1-y}\text{Te}_y$  ( $y = 0, 0.05, 0.1$ , and  $0.15$ ) samples; the dotted lines represent the data for the non-stoichiometric CuAgSe reported in ref. 14.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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